

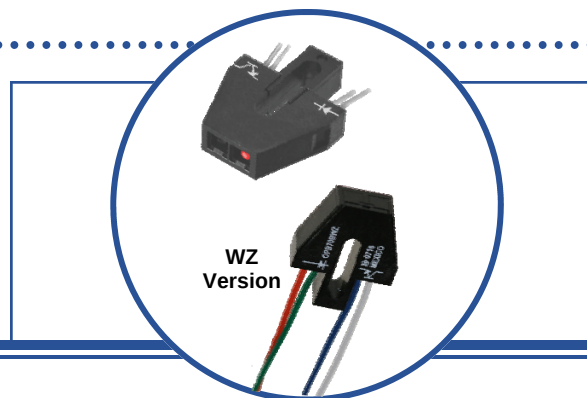
# Reflective Object Sensor

OPB703 through OPB705, OPB703 through OPB705WZ,  
OPB70AWZ through OPB70FWZ



## Features:

- Phototransistor output
- High sensitivity
- Low-cost plastic housing
- Available with lenses for dust protection and ambient light filtration



## Description:

The **OPB703**, **OPB704** and **OPB705** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for PCBoard mounting. The **OPB703WZ**, **OPB704WZ**, **OPB705WZ** and **OPB70BWZ** are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70AWZ** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Photodarlington, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70CWZ through OPB70FWZ** consist of an Visible (Red 640nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor or Rbe Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

Various lens options are available: No lens for the (**OPB703**, **OPB703WZ**), blue window for dust protection for the (**OPB704**, **OPB704WZ**, **OPB70BWZ**) and Aperture lens for improved resolution for the (**OPB705**, **OPB705WZ**, **OPB70AWZ**, **OPB70CWZ** and **OPB70DWZ**).

The phototransistor responds to illumination from the emitter when a reflective object passes within the field of view centered typically at 0.15" (3.8 mm).

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for

## Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor



RoHS

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

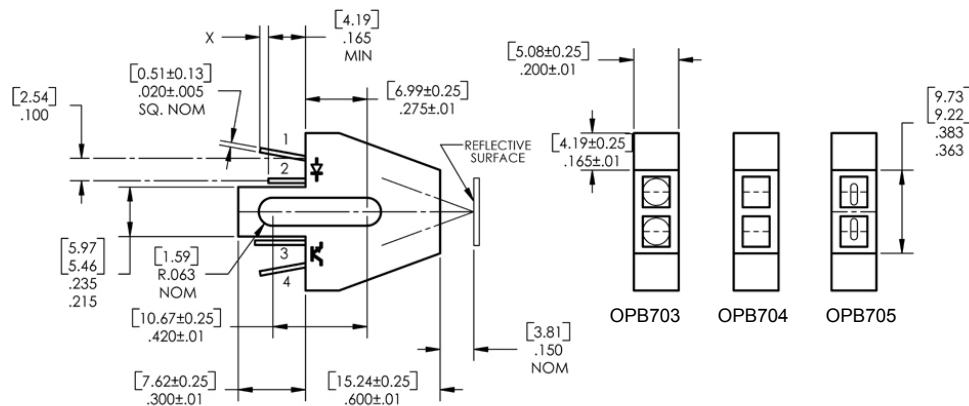
| Ordering Information |          |                |                   |                   |                   |
|----------------------|----------|----------------|-------------------|-------------------|-------------------|
| Part                 | LED Peak |                |                   | Lead or Wire      |                   |
| OPB703               | 890 nm   | Transistor     | None              | 0.160" Leads      |                   |
| OPB703WZ             |          |                |                   | 24" / 26 AWG Wire |                   |
| OPB704               |          |                | Blue Window       | 0.160" Leads      |                   |
| OPB704WZ             |          |                |                   | 24" / 26 AWG Wire |                   |
| OPB705               |          | Aperture       | 0.160" Leads      |                   |                   |
| OPB705WZ             |          |                | 24" / 26 AWG Wire |                   |                   |
| OPB70AWZ             |          |                |                   | Darlington        |                   |
| OPB70BWZ             |          |                |                   | Rbe Transistor    | Blue Window       |
| OPB70CWZ             | 640 nm   | Rbe Transistor |                   | Aperture          | 24" / 26 AWG Wire |
| OPB70DWZ             |          | Transistor     |                   |                   |                   |
| OPB70EWZ             |          | Rbe Transistor |                   | Clear Window      |                   |
| OPB70FWZ             |          | Transistor     |                   |                   |                   |

# Reflective Object Sensor

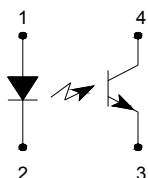
OPB703 through OPB705, OPB703 through OPB705WZ,  
OPB70AWZ through OPB70FWZ



## OPB 703, OPB704, OPB705

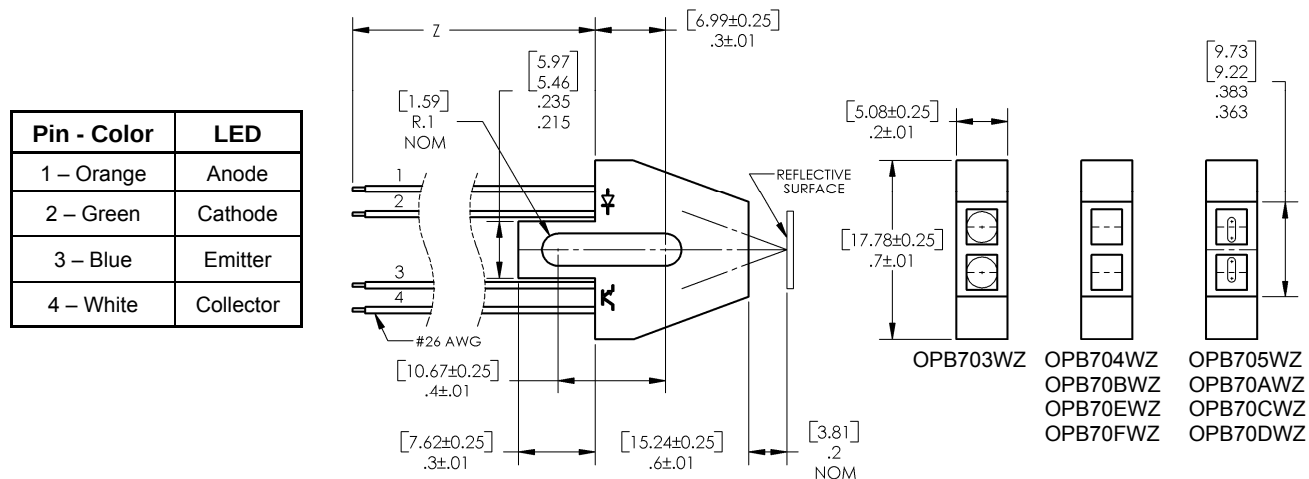


OPB703, OPB704, OPB705

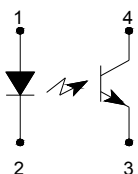


| Pin # | Description | Pin # | Description |
|-------|-------------|-------|-------------|
| 1     | Anode       | 4     | Collector   |
| 2     | Cathode     | 3     | Emitter     |

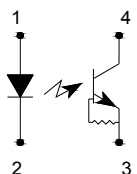
## OPB 703WZ, OPB704WZ, OPB705WZ, OPB70AWZ, OPB70BWZ, OPB70CWZ, OPB70DWZ



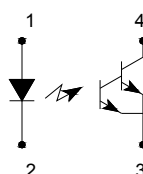
OPB703WZ, OPB704WZ,  
OPB705WZ, OPB70DWZ



OPB703BZ, OPB704CZ



OPB703AWZ



DIMENSIONS ARE IN: [ MILLIMETERS]  
INCHES

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

# Reflective Object Sensor

OPB703 through OPB705, OPB703 through OPB705WZ,  
OPB70AWZ through OPB70FWZ



## Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

|                                                                                              |                                            |
|----------------------------------------------------------------------------------------------|--------------------------------------------|
| Storage Temperature Range                                                                    | $-40^\circ\text{C}$ to $+85^\circ\text{C}$ |
| Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron] | $240^\circ\text{C}^{(1)}$                  |

### Input Diode

|                    |                       |
|--------------------|-----------------------|
| Forward DC Current | 40 mA                 |
| Reverse DC Voltage | 2 V                   |
| Power Dissipation  | $100\text{ mW}^{(2)}$ |

### Output Phototransistor

|                           |                       |
|---------------------------|-----------------------|
| Collector-Emitter Voltage | 30 V                  |
| Emitter-Collector Voltage | 5 V                   |
| Collector DC Current      | 25 mA                 |
| Power Dissipation         | $100\text{ mW}^{(2)}$ |

## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

(OPB703, OPB703WZ, OPB704, OPB704WZ, OPB705, OPB705WZ, OPB70BWZ)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|--------|-----------|-----|-----|-----|-------|-----------------|
|--------|-----------|-----|-----|-----|-------|-----------------|

### Input Diode (See OP265 for additional information — for reference only)

|       |                 |     |   |     |               |                      |
|-------|-----------------|-----|---|-----|---------------|----------------------|
| $V_F$ | Forward Voltage | 0.9 | - | 1.7 | V             | $I_F = 40\text{ mA}$ |
| $I_R$ | Reverse Current | -   | - | 100 | $\mu\text{A}$ | $V_R = 2\text{ V}$   |

### Output Phototransistor (See OP505 for additional information — for reference only)

|               |                                     |    |   |     |    |                                                |
|---------------|-------------------------------------|----|---|-----|----|------------------------------------------------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | 30 | - | -   | V  | $I_{CE} = 100\text{ }\mu\text{A}$              |
| $V_{(BR)ECO}$ | Emitter-Collector Breakdown Voltage | 5  | - | -   | V  | $I_{EC} = 100\text{ }\mu\text{A}$              |
| $I_{CEO}$     | Collector Dark Current              | -  | - | 250 | nA | $V_{CE} = 10\text{ V}$ , $I_F = 0$ , $E_E = 0$ |

### Coupled

|             |                                                                                                  |                      |             |                   |               |                                                                      |
|-------------|--------------------------------------------------------------------------------------------------|----------------------|-------------|-------------------|---------------|----------------------------------------------------------------------|
| $I_{C(ON)}$ | On-State Collector Current<br>OPB703, OPB703WZ<br>OPB704, OPB704WZ<br>OPB705, OPB705WZ, OPB70BWZ | 0.30<br>0.20<br>0.15 | -<br>-<br>- | 2.5<br>2.5<br>1.0 | mA            | $V_{CE} = 5\text{ V}$ , $I_F = 40\text{ mA}$ , $d = 0.15''^{(3)(7)}$ |
| $I_{CX}$    | Crosstalk<br>OPB703, OPB703WZ<br>OPB704, OPB704WZ<br>OPB705, OPB705WZ, OPB70BWZ                  | -<br>-<br>-          | -<br>-<br>- | 20<br>20<br>10    | $\mu\text{A}$ | $V_{CE} = 5\text{ V}$ , $I_F = 40\text{ mA}^{(6)}$                   |

#### Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703, OPB704 and OPB705, derate linearly  $1.67\text{ mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (3) For OPB703WZ, OPB704WZ, OPB705WZ and OPB70BWZ, derate linearly  $1.82\text{ mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (4) The distance from the assembly face to the reflective surface is  $d$ .
- (5) Lower curve is based on a calculated worst-case condition, rather than the conventional  $-2\Omega$  limit.
- (6) Crosstalk ( $I_{CX}$ ) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (7) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (8) All parameters tested using pulse techniques.

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# Reflective Object Sensor

OPB703 through OPB705, OPB703 through OPB705WZ,  
OPB70AWZ through OPB70FWZ



## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (OPB70AWZ)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|--------|-----------|-----|-----|-----|-------|-----------------|
|--------|-----------|-----|-----|-----|-------|-----------------|

**Input Diode** (See OP265 for additional information — for reference only)

|       |                 |   |   |     |               |                     |
|-------|-----------------|---|---|-----|---------------|---------------------|
| $V_F$ | Forward Voltage | - | - | 1.7 | V             | $I_F = 40\text{mA}$ |
| $I_R$ | Reverse Current | - | - | 100 | $\mu\text{A}$ | $V_R = 2\text{V}$   |

**Output PhotoDarlington** (See OP535 for additional information — for reference only)

|               |                                     |    |   |     |    |                                               |
|---------------|-------------------------------------|----|---|-----|----|-----------------------------------------------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | 15 | - | -   | V  | $I_{CE} = 1.0\text{mA}$ , $E_E = 0$           |
| $V_{(BR)ECO}$ | Emitter-Collector Breakdown Voltage | 5  | - | -   | V  | $I_{EC} = 100\mu\text{A}$ , $E_E = 0$         |
| $I_{CEO}$     | Collector Dark Current              | -  | - | 250 | nA | $V_{CE} = 10\text{V}$ , $I_F = 0$ , $E_E = 0$ |

### Coupled

|             |                            |      |   |      |               |                                                                                     |
|-------------|----------------------------|------|---|------|---------------|-------------------------------------------------------------------------------------|
| $I_{C(ON)}$ | On-State Collector Current | 5.0  | - | 26.0 | mA            | $V_{CE} = 5\text{V}$ , $I_F = 40\text{mA}$ , $d = 0.15''$ <sup>(2)(6)</sup>         |
| $V_{(SAT)}$ | Saturation Voltage         | 0.60 | - | 1.15 | V             | $I_{C(ON)} = 400\mu\text{A}$ , $I_F = 40\text{mA}$ , $d = 0.15''$ <sup>(2)(6)</sup> |
| $I_{CX}$    | Crosstalk                  | -    | - | 25   | $\mu\text{A}$ | $V_{CE} = 5\text{V}$ , $I_F = 40\text{mA}$ <sup>(5)</sup>                           |

#### Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly  $1.82\text{ mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (3) The distance from the assembly face to the reflective surface is  $d$ .
- (4) Lower curve is based on a calculated worst-case condition, rather than the conventional  $-2\Omega$  limit.
- (5) Crosstalk ( $I_{CX}$ ) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

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# Reflective Object Sensor

OPB703 through OPB705, OPB703 through OPB705WZ,  
OPB70AWZ through OPB70FWZ



## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

(OPB70CWZ, OPB70DWZ, OPB70EWZ and OPB70FWZ)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|--------|-----------|-----|-----|-----|-------|-----------------|
|--------|-----------|-----|-----|-----|-------|-----------------|

**Input Diode** (See OVLAS6CB8 for additional information — for reference only)

|       |                 |     |   |     |               |                     |
|-------|-----------------|-----|---|-----|---------------|---------------------|
| $V_F$ | Forward Voltage | 1.6 | - | 2.5 | V             | $I_F = 40\text{mA}$ |
| $I_R$ | Reverse Current | -   | - | 100 | $\mu\text{A}$ | $V_R = 2\text{V}$   |

**Output Phototransistor** (See OP505 for additional information — for reference only)

|               |                                     |     |   |     |    |                                                           |
|---------------|-------------------------------------|-----|---|-----|----|-----------------------------------------------------------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | 30  | - | -   | V  | $I_{CE} = 100\text{ }\mu\text{A}$ , $I_F = 0$ , $E_E = 0$ |
| $V_{(BR)ECO}$ | Emitter-Collector Breakdown Voltage | 0.4 | - | -   | V  | $I_{EC} = 100\text{ }\mu\text{A}$ , $I_F = 0$ , $E_E = 0$ |
| $I_{CEO}$     | Collector Dark Current              | -   | - | 250 | nA | $V_{CE} = 10\text{V}$ , $I_F = 0$ , $E_E = 0$             |

## Coupled

|             |                            |      |   |     |               |                                                                                    |
|-------------|----------------------------|------|---|-----|---------------|------------------------------------------------------------------------------------|
| $I_{C(ON)}$ | On-State Collector Current | 0.10 | - | 1.0 | mA            | $V_{CE} = 5\text{V}$ , $I_F = 40\text{mA}$ , $d = 0.15''^{(2)(6)}$                 |
| $V_{(SAT)}$ | Saturation Voltage         | -    | - | 0.4 | V             | $I_{C(ON)} = 400\text{ }\mu\text{A}$ , $I_F = 40\text{mA}$ , $d = 0.15''^{(2)(6)}$ |
| $I_{CX}$    | Crosstalk                  | -    | - | 0.1 | $\mu\text{A}$ | $V_{CE} = 5\text{V}$ , $I_F = 40\text{mA}^{(5)}$                                   |

## Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703WZ, OPB704WZ, OPB705WZ and OPB70BWZ, derate linearly  $1.82\text{ mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (3) The distance from the assembly face to the reflective surface is  $d$ .
- (4) Lower curve is based on a calculated worst-case condition, rather than the conventional  $-2\Omega$  limit.
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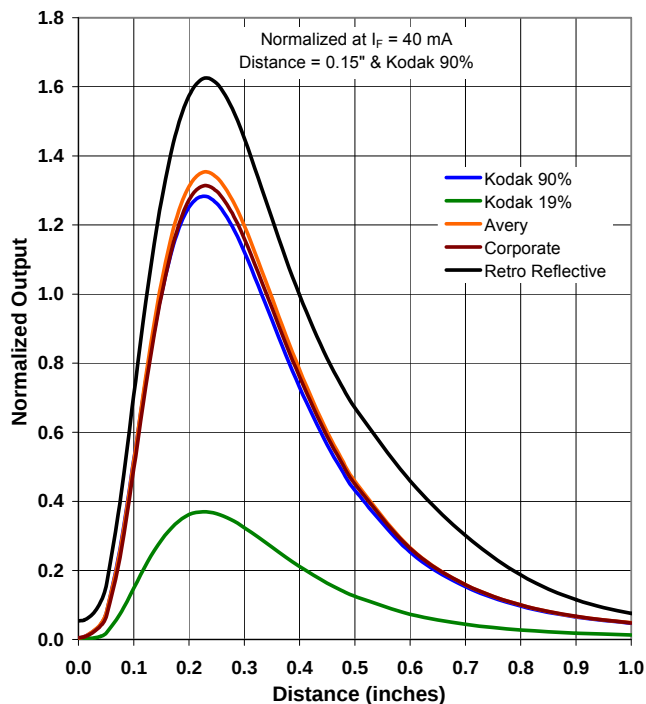
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# Reflective Object Sensor

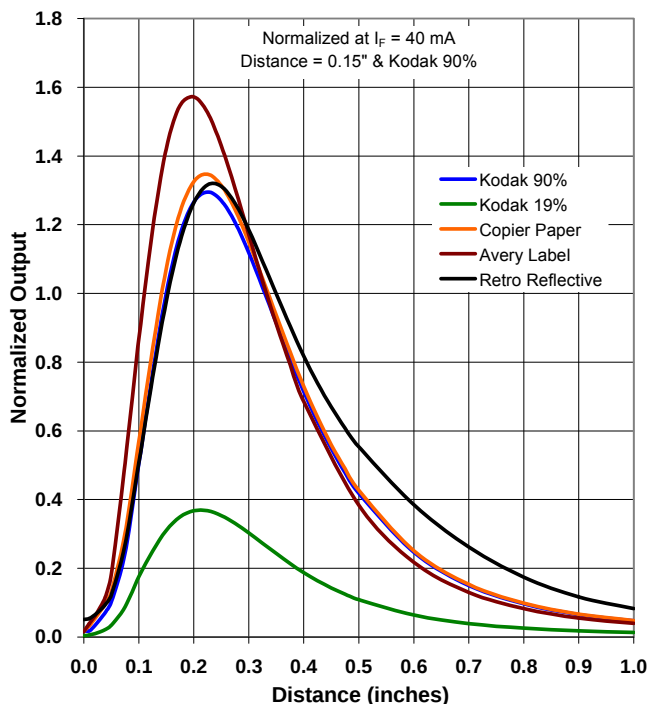
OPB703 through OPB705, OPB703 through OPB705WZ,  
OPB70AWZ through OPB70FWZ



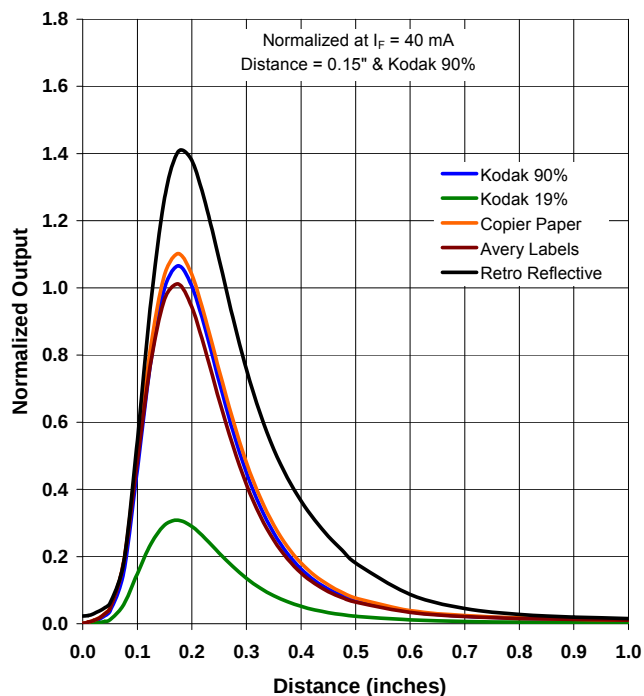
OPB703—Output Distance



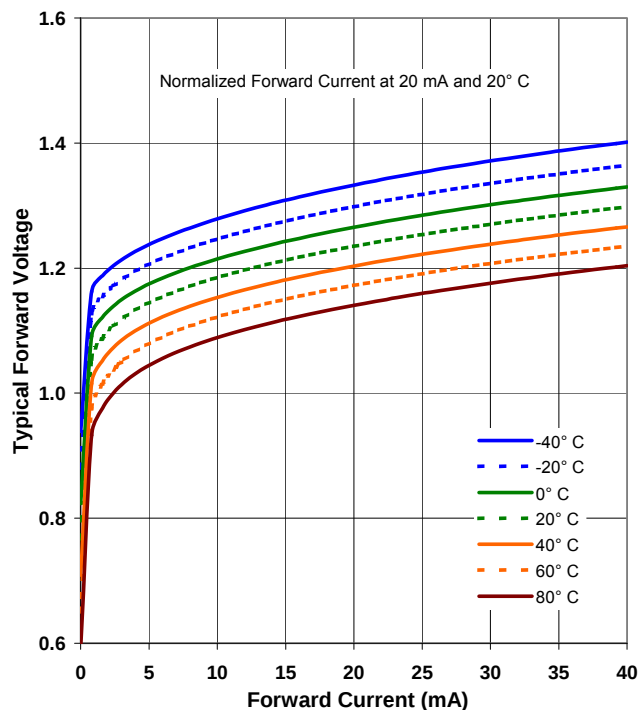
OPB704, OPB70B—Output Distance



OPB705, OPB70A, OPB70C, OPB70D—Output Distance



Forward Voltage vs Forward Current vs Temp



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